Timestamp	Email address	Score	Name	University / institutions	Designation	Mobile Number	Which of the following well-known semiconductor	In a bandpass filter, the	In Oscilloscope shows	A sinusoidal current	Half of ac	Some	are useful for	Which of the following	Unity	Half-wave rectifier	Full-wave rectifier	The energy gap	The mobility of electrons	The conductivity of a	The Hall effect	ensures	The depletion region	Half-wave voltage of a	A silicon	reverse temperature	of	Silicon PN diode is	frequently	Zener	operates on the	The LASER	operates	Gallium	LEDs	emit radiation	For a bipolar junction	The	input	impedance of a	An SCR	is a	semiconductor	Where	the following	The	efficiency of a full-wave	Zener diode	short	voltage	regulator.	the diode	regulates	as long as it is kept in
23/05/2020 11:09:24	shanthamani8@gmail.c		90 – 100	Shani	Islamiah College (Autono	Research Scholars	9944551721	(a) ceramic	(a) 0.35kHz	(a) 0.707A	(a) 0.5Wm	(b) 1 to 10 V	(c) high frequency	(a) 1	(b) 0.5	(c) 1.1	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) Forward bias	(a) 0.6V	(a) 0.6V	(b) working diode for high	photo sensitive active	(a) warm	(c) IR region	(a) 1 to 1.5	(a) above 2800	(b) forward PN junctions	(d) LiT	(b) 91.2%	(c) reverse bias
23/05/2020 11:29:30	thasanamohamed@gmail.c		90 – 100	M Tamizan Ahmed	Islamiah College (Autono	Research Scholars	7339164871	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(c) mid frequency	(c) Relay	(c) 1.45 V	(b) 0.5V	(a) n-ty	(c) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) Forward bias	(b) 0.6V	(c) 0.6V	(d) peak detector	(a) diffusion	(b) LED	(c) IR region	(b) 1 to 10	(c) 200 to 400 KO	(a) low PN junctions	(d) BCR	(b) 91.2%	(d) unloaded
23/05/2020 12:40:20	aqamohamed07@gmail.com		90 – 100	Sithara. M	Thiruvarur university	Students	6374589261	(c) metallic	(a) 2.35μ Siemens	(c) 0.707 A	(a) 0.5Wm	(a) 1 TO 7 V	(b) high frequency	(c) Relay	(c) 1.45 V	(b) mA/V	(c) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(b) voltage regulator	(b) reconstruction	(a) warm	(a) UV region	(b) 1 to 100	(a) above 2800	(a) low PN junctions	(d) LiT	(c) 90%	(b) forward bias
23/05/2020 12:43:37	ayaan0008@gmail.com		90 – 100	Ayaan S	Thiruvarur university	Students	6382627345	(b) metallic	(a) 2.35μ Siemens	(a) 0.707 A	(a) 0.5Wm	(a) 1 TO 7 V	(b) high frequency	(c) Relay	(c) 1.45 V	(b) 0.5V	(b) mA/V	(c) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(b) voltage regulator	(b) reconstruction	(a) warm	(a) UV region	(b) 1 to 100	(a) above 2800	(a) low PN junctions	(d) LiT	(c) 90%	(b) forward bias
23/05/2020 12:44:27	Thasanamohamed@g		90 – 100	M Tamizan Ahmed	Islamiah College (Autono	Research Scholars	9944551721	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(c) mid frequency	(c) Relay	(c) 1.45 V	(b) 0.5V	(b) mA/V	(c) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.6V	(c) 0.6V	(b) voltage regulator	(b) reconstruction	(a) warm	(a) UV region	(b) 1 to 10	(c) 200 to 400 KO	(a) low PN junctions	(d) BCR	(b) 91.2%	(d) unloaded
23/05/2020 12:54:47	Thasanthi0505@gmail.c		90 – 100	T. Prasanth	University	Students	6383520948	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(b) high frequency	(a) Toggle switch	(a) 1.5 V	(c) mA/V	(c) n-type	(c) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) P-type semiconductor	(d) all of these	(a) 0.3V	(c) 0.6V	(b) voltage regulator	(c) photo diode active	(c) LED	(a) UV region	(b) 1 to 100	(a) above 2800	(a) low PN junctions	(b) TRIAC	(b) 91.2%	(b) forward bias
23/05/2020 13:24:47	aadishamed2006@gmail.c		90 – 100	S. Asad Ahmed	Islamiah college Academic	Students	8300138127	(d) all of them	(a) 2.35μ Siemens	(a) 0.707 A	(c) 0.5Wm	(a) 1 TO 7 V	(d) very high frequency	(a) Toggle switch	(a) 1.5 V	(c) mA/V	(a) n-type	(d) changing its shape	(a) n-type	(a) Zener diode	(a) 0.3V	(b) 0.3V	(d) working diode for high	photo sensitive active	(d) photosensitive	(a) UV region	(b) 1 to 100	(c) 200 to 400 KO	(a) low PN junctions	(d) LiT	(c) 40.6%	(c) loaded
23/05/2020 13:26:07	Ashfaqahmed.ahmed.ma		90 – 100	Ashfaq Ahmed Ansari M	Islamiah College Academic	Research Scholars	9944551721	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(c) mid frequency	(c) Relay	(c) 1.45 V	(b) 0.5V	(b) mA/V	(c) n-type	(c) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(b) voltage regulator	(c) photo diode active	(c) LED	(a) UV region	(b) 1 to 100	(a) above 2800	(a) low PN junctions	(d) LiT	(c) 90%	(b) forward bias
23/05/2020 13:30:08	Yaboob.ibn		90 – 100	Yaboob. ibn	University	Students	6384867452	(a) none	(a) 2.35μ Siemens	(a) 0.707 A	(a) 0.5Wm	(a) 1 TO 7 V	(b) high frequency	(b) crystal breaker	(c) 1.45 V	(c) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(b) 0.3V	(d) working diode for high	photo sensitive active	(c) LED	(b) IR region	(d) 100 to 1000	(a) above 2800	(c) low PN junctions	(a) BCR	(b) 91.2%	(b) forward bias
23/05/2020 14:00:55	Ungaiyan.06@gmail.com		90 – 100	G.Lakshmi	Islamiah College	Students	9003875420	(a) none	(a) 2.35μ Siemens	(c) 0.807 A	(c) 0.5Wm	(a) 1 TO 7 V	(b) high frequency	(c) Relay	(a) 1.5 V	(c) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(d) all of these	(a) 0.3V	(b) 0.3V	(b) working diode for high	photo sensitive active	(c) LED	(b) IR region	(a) 1 to 1.5	(a) above 2800	(a) low PN junctions	(d) LiT	(b) 91.2%	(b) forward bias
23/05/2020 14:05:01	mozakkir01@gmail.com		90 – 100	M. Mozakkir	Islamiah college	Students	9629367750	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(c) 0.5Wm	(c) 10 -90 V	(a) low frequency	(c) crystal breaker	(a) 1.5 V	(c) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(d) all of these	(a) 0.3V	(b) 0.3V	(c) current generator	(c) photo diode active	(c) LED	(b) IR region	(a) 1 to 1.5	(a) above 2800	(a) low PN junctions	(d) LiT	(b) 91.2%	(b) forward bias
23/05/2020 14:06:05	abdulkarim.ahamed@gm		90 – 100	Abdul-kari. J	Islamiah college	Students	9626867824	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(a) 1 TO 7 V	(b) high frequency	(d) OPPOT switch	(a) 1.5 V	(c) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(d) all of these	(a) 0.3V	(b) 0.3V	(a) voltage regulator	(d) carrier flow	(c) LED	(d) none of these	(a) 1 to 1.5	(a) above 2800	(b) low PN junctions	(a) BCR	(d) 100%	(b) forward bias
23/05/2020 14:08:19	Mohamedsulaiman.c		90 – 100	Mohamed Sulaiman C	Islamiah College (Autono	Research Scholars	9944551721	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(c) mid frequency	(c) Relay	(c) 1.45 V	(b) 0.5V	(b) mA/V	(c) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(b) voltage regulator	(b) reconstruction	(a) warm	(a) UV region	(b) 1 to 100	(a) above 2800	(a) low PN junctions	(d) LiT	(c) 90%	(b) forward bias
23/05/2020 14:20:10	nazeerahamed@gmail.c		90 – 100	Nazeerahamed. S	Islamiah college	Research Scholars	9677790151	(a) none	(a) 2.35μ Siemens	(a) 0.707 A	(a) 0.5Wm	(a) 1 TO 7 V	(b) high frequency	(b) crystal breaker	(b) 10 -90 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(c) Reverse Bias	(a) 0.3V	(c) 0.6V	(b) voltage regulator	(c) photo diode active	(c) LED	(b) IR region	(a) 1 to 1.5	(a) above 2800	(c) low PN junctions	(b) TRIAC	(a) 40.6%	(b) forward bias
23/05/2020 14:36:12	ajaya008@gmail.com		90 – 100	Ajaya R	Islamiah college	Students	9952488524	(c) resistant	(c) 3.35μ Siemens	(c) 0.707 A	(a) 0.5Wm	(a) 1 TO 7 V	(b) high frequency	(d) OPPOT switch	(b) 10 -90 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(c) Reverse Bias	(a) 0.3V	(b) 0.3V	(a) voltage regulator	(c) photo diode active	(c) LED	(b) IR region	(b) 1 to 10	(a) above 2800	(c) low PN junctions	(d) LiT	(b) 91.2%	(b) forward bias
23/05/2020 17:11:08	mohamed0108@gmail.c		90 – 100	M. Mohan	Thiruvarur	Students	9786886527	(a) none	(a) 2.35μ Siemens	(c) 0.707 A	(a) 0.5Wm	(a) 1 TO 7 V	(b) high frequency	(c) Relay	(a) 1.5 V	(c) mA/V	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(b) 0.3V	(b) working diode for high	photo sensitive active	(a) warm	(c) IR region	(a) 1 to 1.5	(a) above 2800	(b) low PN junctions	(d) LiT	(b) 91.2%	(b) forward bias
23/05/2020 17:20:05	aqibahmed@gmail.com		90 – 100	Rakesh. M	Islamiah college	Students	6383126780	(b) resistant	(c) 3.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(a) 1 TO 7 V	(c) mid frequency	(a) Toggle switch	(c) 1.45 V	(d) none of these	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(c) Reverse Bias	(a) 0.3V	(a) 0.6V	(c) current generator	(a) diffusion	(c) photodiode	(b) visible region	(a) 1 to 1.5	(c) 200 to 400 KO	(c) low PN junctions	(b) TRIAC	(b) 91.2%	(b) forward bias
23/05/2020 17:21:13	Ashfaqahmed.ansari		90 – 100	Ashfaq Ahmed Ansari	Islamiah College	Research Scholars	9944551721	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(c) mid frequency	(c) Relay	(c) 1.45 V	(b) 0.5V	(b) mA/V	(c) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(b) voltage regulator	(b) reconstruction	(a) warm	(a) UV region	(b) 1 to 100	(a) above 2800	(a) low PN junctions	(d) BCR	(b) 91.2%	(d) unloaded
23/05/2020 17:27:12	Tulsi.thilakam		90 – 100	Tulsi Thilakam	Deenanath University	Research Scholars	9944944588	(c) metallic	(a) 2.35μ Siemens	(c) 0.707 A	(a) 0.5Wm	(a) 1 TO 7 V	(a) low frequency	(c) Relay	(c) 1.45 V	(b) 0.5V	(b) mA/V	(c) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(c) current generator	(c) photo diode active	(c) photodiode	(b) visible region	(a) 1 to 1.5	(c) 200 to 400 KO	(c) low PN junctions	(b) TRIAC	(b) 91.2%	(c) loaded
23/05/2020 17:27:53	hashaanahmed1234@gm		90 – 100	S.HASHASAN	Islamiah college	Students	8610820890	(a) none	(c) 3.35μ Siemens	(c) 0.707 A	(a) 0.5Wm	(a) 1 TO 7 V	(b) high frequency	(c) Relay	(c) 1.45 V	(c) mA/V	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(a) 0.6V	(d) working diode for high	diffusion	(c) LED	(b) IR region	(b) 1 to 10	(a) above 2800	(c) low PN junctions	(c) DIAC	(b) 91.2%	(b) forward bias
23/05/2020 19:42:05	arulselvanger1@gmail.c		90 – 100	Arul-S.	Islamiah college (autoge	Students	6384867527	(c) metallic	(c) 3.35μ Siemens	(c) 0.807 A	(c) 0.5Wm	(c) mid frequency	(d) OPPOT switch	(b) 10 -90 V	(c) 1.1 mA	(d) 1 V	(c) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(c) Reverse Bias	(d) 1 V	(a) 0.6V	(a) voltage regulator	(d) carrier flow	(c) LED	(a) UV region	(b) 1 to 10	(c) 200 to 400 KO	(b) low PN junctions	(d) BCR	(b) 91.2%	(b) forward bias
23/05/2020 19:50:55	gnanakumarmsc.18@gm		90 – 100	Dr. Charles gnana	Islamiah College (Autono	Research Scholars	9750047042	(d) all of them	(c) 3.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(b) high frequency	(d) OPPOT switch	(a) 1.5 V	(c) 1.1 mA	(d) 1 V	(b) 0.3V	(b) 0.3V	(b) decreasing the temperature	(d) minimum semiconductor	(d) all of these	(d) 1 V	(b) 0.3V	(b) working diode for high	photo sensitive active	(c) LED	(a) UV region	(a) 1 to 1.5	(a) above 2800	(b) low PN junctions	(a) BCR	(a) 40.6%	(b) unloaded
23/05/2020 20:24:30	aadishamed2006@gmail.c		90 – 100	S. Asad Ahmed	Islamiah college (autoge	Students	9123455420	(a) none	(c) 3.35μ Siemens	(c) 0.807 A	(c) 0.5Wm	(a) 1 TO 7 V	(a) low frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) minimum semiconductor	(b) Forward bias	(a) 0.3V	(a) 0.6V	(b) working diode for high	photo sensitive active	(c) LED	(b) IR region	(a) 1 to 1.5	(a) above 2800	(b) low PN junctions	(d) LiT	(b) 91.2%	(b) reverse bias
23/05/2020 20:55:13	ashikahamed@gmail.c		90 – 100	B.E.UNIVERSUNIVERSI	Sharafiya breast jam ceila	Students	9944551721	(c) metallic	(c) 3.35μ Siemens	(c) 0.807 A	(c) 0.5Wm	(a) 1 TO 7 V	(b) high frequency	(a) Toggle switch	(a) 1.5 V	(b) mA/V	(d) none of these	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) Reverse Bias	(a) 0.3V	(a) 0.6V	(d) working diode for high	photo sensitive active	(c) LED	(d) none of these	(b) 1 to 10	(c) 200 to 400 KO	(a) low PN junctions	(d) LiT	(b) 91.2%	(b) reverse bias
23/05/2020 21:01:16	Ashfaqahmed.ansari		90 – 100	Ashfaq Ahmed Ansari	Islamiah College (Autono	Research Scholars	9944551721	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(c) mid frequency	(c) Relay	(c) 1.45 V	(b) 0.5V	(b) mA/V	(c) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(b) voltage regulator	(b) reconstruction	(a) warm	(a) UV region	(b) 1 to 100	(a) above 2800	(a) low PN junctions	(d) LiT	(c) 90%	(b) forward bias
23/05/2020 22:12:16	Shanbakhtar.ibrahim		90 – 100	Shanbakhtar Ibrahim	Govt.p.g. college (autono	Research Scholars	9751425353	(d) all of them	(c) 3.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(a) 1 TO 7 V	(c) mid frequency	(b) crystal breaker	(d) 90-V	(c) 1.1 mA	(c) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(c) Reverse Bias	(a) 0.3V	(a) 0.6V	(a) voltage regulator	(c) photo diode active	(c) LED	(b) visible region	(a) 1 to 1.5	(c) 200 to 400 KO	(b) TRIAC	(c) 100%	(d) unloaded
24/05/2020 07:02:42	mohamedsamsu.2020@gr		90 – 100	N.Mohamed Samsu	ISLAMIAH COLLEGE (Au	Students	9944338791	(d) all of them	(c) 3.35μ Siemens	(c) 0.707 A	(a) 0.5Wm	(b) 1 to 10 V	(b) high frequency	(d) OPPOT switch	(c) 1.45 V	(d) none of these	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(c) Reverse Bias	(c) 0.6V	(d) 1 V	(b) working diode for high	photo sensitive active	(c) LED	(d) none of these	(a) 1 to 1.5	(a) above 2800	(c) low PN junctions	(b) TRIAC	(b) 91.2%	(b) forward bias
24/05/2020 08:24:42	Ashfaqahmed.ansari.2		90 – 100	Ashfaq Ahmed Ansari	Islamiah College (Autono	Research Scholars	+919944551721	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(c) mid frequency	(c) Relay	(c) 1.45 V	(b) 0.5V	(b) mA/V	(c) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(b) working diode for high	photo sensitive active	(a) warm	(c) IR region	(a) 1 to 1.5	(a) above 2800	(c) low PN junctions	(d) LiT	(b) 91.2%	(b) reverse bias
24/05/2020 09:24:41	yusbabar.2020@gmail.c		90 – 100	yusbabar.S.H	Bharathiar	Students	9944551721	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(d) very high frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(b) working diode for high	photo sensitive active	(a) warm	(c) IR region	(a) 1 to 1.5	(a) above 2800	(c) low PN junctions	(d) LiT	(b) 91.2%	(b) reverse bias
24/05/2020 09:54:15	ameenjamesmsc@gmail.c		90 – 100	Ameen James	Islamiah College (Autono	Research Scholars	9944551721	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(b) high frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(d) peak detector	(c) reconstruction	(a) warm	(c) IR region	(a) 1 to 1.5	(c) 200 to 400 KO	(b) TRIAC	(c) 100%	(b) forward bias
24/05/2020 10:41:11	ayaan0008@gmail.com		90 – 100	Ayaan S	Thiruvarur university	Students	6382627345	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(c) mid frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(d) peak detector	(c) reconstruction	(a) warm	(c) IR region	(a) 1 to 1.5	(c) 200 to 400 KO	(b) TRIAC	(c) 100%	(b) forward bias
24/05/2020 12:41:33	Ashfaqahmed.ansari		90 – 100	A.M.Mohammed Ansari	Islamiah College	Students	9944551721	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(b) high frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(b) working diode for high	photo sensitive active	(a) warm	(c) IR region	(a) 1 to 1.5	(a) above 2800	(c) low PN junctions	(d) LiT	(b) 91.2%	(b) forward bias
24/05/2020 13:41:17	Ashfaqahmed.ansari		90 – 100	Ashfaq Ahmed Ansari	Islamiah College (Autono	Research Scholars	9944551721	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(c) mid frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(b) working diode for high	photo sensitive active	(a) warm	(c) IR region	(a) 1 to 1.5	(a) above 2800	(c) low PN junctions	(d) LiT	(b) 91.2%	(b) reverse bias
24/05/2020 16:27:01	T.prasanthkumar.1@gm		90 – 100	T. Prasanth	Thiruvarur	Students	6383520948	(a) none	(c) 3.35μ Siemens	(c) 0.707 A	(a) 0.5Wm	(a) 1 TO 7 V	(d) very high frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(b) working diode for high	photo sensitive active	(a) warm	(c) IR region	(a) 1 to 1.5	(a) above 2800	(c) low PN junctions	(d) LiT	(b) 91.2%	(b) forward bias
24/05/2020 18:52:07	nazeerahamed1@gmail.c		90 – 100	NAZEERAHAMED. S	DR.MALCALCHO.NUSEI	Research Scholars	9944140979	(c) metallic	(c) 3.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(b) high frequency	(b) crystal breaker	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) minimum semiconductor	(b) Forward bias	(a) 0.3V	(c) 0.6V	(d) photosensitive	(c) reconstruction	(a) warm	(c) IR region	(a) 1 to 1.5	(c) 200 to 400 KO	(c) low PN junctions	(d) LiT	(b) 91.2%	(b) reverse bias
24/05/2020 19:17:14	mohamedjamil.2020@gm		90 – 100	M.MOHAMEDJAMIL	Vivekananda Arts and	Research Scholars	7598882182	(a) none	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(a) 1 TO 7 V	(b) high frequency	(a) Toggle switch	(a) 1.5 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(c) Reverse Bias	(a) 0.3V	(a) 0.6V	(b) working diode for high	photo sensitive active	(c) photodiode	(b) visible region	(a) 1 to 1.5	(c) 200 to 400 KO	(c) low PN junctions	(b) TRIAC	(b) 91.2%	(b) forward bias
24/05/2020 19:27:42	shankaran.17.2@gmail.c		90 – 100	R. Shankar Kumar	Thiruvarur university	Students	9751756105	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(c) 0.5Wm	(a) 1 TO 7 V	(a) low frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(c) Reverse Bias	(c) 0.6V	(d) 1 V	(b) working diode for high	photo sensitive active	(c) LED	(b) IR region	(b) 1 to 10	(c) 200 to 400 KO	(a) low PN junctions	(d) BCR	(b) 91.2%	(b) reverse bias
24/05/2020 19:28:14	Ashfaqahmed.ansari		90 – 100	Ashfaq Ahmed Ansari	Islamiah College (Autono	Research Scholars	9944551721	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(b) high frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(b) working diode for high	photo sensitive active	(a) warm	(c) IR region	(a) 1 to 1.5	(a) above 2800	(c) low PN junctions	(d) LiT	(b) 91.2%	(b) reverse bias
24/05/2020 20:08:18	M.Sultanahamed		90 – 100	M.Sultanahamed	Thiruvarur university	Students	9600620000	(a) none	(c) 3.35μ Siemens	(c) 0.707 A	(a) 0.5Wm	(b) 1 to 10 V	(b) high frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(d) peak detector	(c) photo sensitive active	(a) warm	(c) IR region	(a) 1 to 1.5	(a) above 2800	(c) low PN junctions	(d) LiT	(b) 91.2%	(b) reverse bias
24/05/2020 20:09:08	M. Sadhasivam		90 – 100	M. Sadhasivam	Thiruvarur university	Students	9600620000	(a) none	(c) 3.35μ Siemens	(c) 0.707 A	(a) 0.5Wm	(b) 1 to 10 V	(b) high frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(d) peak detector	(c) photo sensitive active	(a) warm	(c) IR region	(a) 1 to 1.5	(a) above 2800	(c) low PN junctions	(d) LiT	(b) 91.2%	(b) reverse bias
24/05/2020 20:09:58	M. Sadhasivam		90 – 100	M. Sadhasivam	Thiruvarur university	Students	9600620000	(a) none	(c) 3.35μ Siemens	(c) 0.707 A	(a) 0.5Wm	(b) 1 to 10 V	(b) high frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(d) peak detector	(c) photo sensitive active	(a) warm	(c) IR region	(a) 1 to 1.5	(a) above 2800	(c) low PN junctions	(d) LiT	(b) 91.2%	(b) reverse bias
24/05/2020 20:50:08	M. Sadhasivam Isaac		90 – 100	Isaac Sadhasivam	Islamiah college (Autono	Students	8617930687	(b) resistant	(c) 3.35μ Siemens	(c) 0.807 A	(c) 0.5Wm	(a) Toggle switch	(a) low frequency	(c) Relay	(c) 1.45 V	(b) 0.5V	(b) mA/V	(c) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(c) Reverse Bias	(c) 0.6V	(d) 1 V	(b) working diode for high	photo sensitive active	(d) none of these	(b) 1 to 10	(c) 200 to 400 KO	(a) low PN junctions	(d) LiT	(c) 90%	(b) reverse bias
24/05/2020 20:55:51	Ashfaqahmed.ansari		90 – 100	Ashfaq Ahmed Ansari	Islamiah College (Autono	Research Scholars	9944551721	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(b) high frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(b) working diode for high	photo sensitive active	(a) warm	(c) IR region	(a) 1 to 1.5	(a) above 2800	(c) low PN junctions	(d) LiT	(b) 91.2%	(b) reverse bias
25/05/2020 10:20:57	S.Yusufahamed		90 – 100	S.Yusufahamed	Vivekananda Arts and	Students	9750547362	(b) resistant	(c) 3.35μ Siemens	(c) 0.807 A	(c) 0.5Wm	(c) 10 -90 V	(b) high frequency	(d) OPPOT switch	(a) 1.5 V	(c) 1.1 mA	(c) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) minimum semiconductor	(d) all of these	(a) 0.3V	(c) 0.6V	(d) photosensitive	(c) reconstruction	(a) warm	(c) IR region	(a) 1 to 1.5	(c) 200 to 400 KO	(c) low PN junctions	(b) TRIAC	(b) 91.2%	(b) forward bias
25/05/2020 10:40:08	Ashfaqahmed.ansari		90 – 100	Ashfaq Ahmed Ansari	Islamiah College (Autono	Research Scholars	9944551721	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(b) high frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(b) working diode for high	photo sensitive active	(a) warm	(c) IR region	(a) 1 to 1.5	(a) above 2800	(c) low PN junctions	(d) LiT	(b) 91.2%	(b) reverse bias
25/05/2020 11:49:55	T.Ashfaqahmed		90 – 100	T.Ashfaq Ahmed	Islamiah College	Students	7010138543	(c) metallic	(a) 2.35μ Siemens	(c) 0.707 A	(a) 0.5Wm	(b) 1 to 10 V	(b) high frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) metals	(b) Forward bias	(a) 0.3V	(c) 0.6V	(d) photosensitive	(c) reconstruction	(a) warm	(c) IR region	(a) 1 to 1.5	(a) above 2800	(c) low PN junctions	(d) LiT	(b) 91.2%	(b) reverse bias
25/05/2020 11:55:15	Ashfaqahmed.ansari		90 – 100	Ashfaq Ahmed Ansari	Islamiah College (autoge	Students	9944551721	(c) metallic	(a) 2.35μ Siemens	(c) 0.807 A	(a) 0.5Wm	(b) 1 to 10 V	(b) high frequency	(c) Relay	(c) 1.45 V	(c) 1.1 mA	(b) mA/V	(a) n-type	(b) n-type	(c) 1.5	(a) 1	(b) decreasing the temperature	(c) minimum semiconductor	(b) Forward bias	(a) 0.3V	(c) 0.6V	(d) photosensitive	(c) reconstruction	(a) warm	(c) IR region	(a) 1 to 1.5	(c) 200 to 400 KO	(c) low PN junctions	(d) LiT	(b) 91.2%	(b) reverse bias
25/05/2020 12:09:08	PRAVEEN KUMAR.S		90 – 100	PRAVEEN KUMAR.S	Islamiah college	Students	8300138127	(b) resistant	(c) 3.35μ Siemens